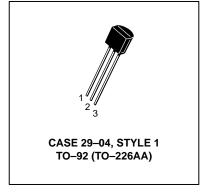
## **Switching Transistor** PNP Silicon

# COLLECTOR 3 BASE 1 EMITTER

#### **MAXIMUM RATINGS**

| Rating  | Symbol                            | Value       | Unit           |
|---|-----------------------------------|-------------|----------------|
| Collector-Emitter Voltage   | VCEO                              | -12         | Vdc            |
| Collector-Base Voltage  | VCBO                              | -12         | Vdc            |
| Emitter-Base Voltage  | VEBO                              | -4.0        | Vdc            |
| Collector Current — Continuous  | IC                                | -80         | mAdc           |
| Total Device Dissipation @ T <sub>A</sub> = 25°C<br>Derate above 25°C | PD                                | 625<br>5.0  | mW<br>mW/°C    |
| Total Device Dissipation @ T <sub>C</sub> = 25°C<br>Derate above 25°C | PD                                | 1.5<br>12   | Watts<br>mW/°C |
| Operating and Storage Junction<br>Temperature Range                   | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C             |

### **MPS3640**



#### THERMAL CHARACTERISTICS

| Characteristic                          | Symbol          | Max  | Unit |
|---|-----------------|------|------|
| Thermal Resistance, Junction to Ambient | $R_{	heta JA}$  | 200  | °C/W |
| Thermal Resistance, Junction to Case    | $R_{\theta}$ JC | 83.3 | °C/W |

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristic   | Symbol    | Min  | Max           | Unit |
|--|-----------|------|---------------|------|
| OFF CHARACTERISTICS  |           |      |               |      |
| Collector-Emitter Breakdown Voltage (I <sub>C</sub> = -100 μAdc, V <sub>BE</sub> = 0)  | V(BR)CES  | -12  | _             | Vdc  |
| Collector-Emitter Sustaining Voltage <sup>(1)</sup> (I <sub>C</sub> = -10 mAdc, I <sub>B</sub> = 0)                                      | VCEO(sus) | -12  | _             | Vdc  |
| Collector-Base Breakdown Voltage (I <sub>C</sub> = -100 μAdc, I <sub>E</sub> = 0)  | V(BR)CBO  | -12  | _             | Vdc  |
| Emitter–Base Breakdown Voltage (I <sub>E</sub> = –100 μAdc, I <sub>C</sub> = 0)  | V(BR)EBO  | -4.0 | _             | Vdc  |
| Collector Cutoff Current $(V_{CE} = -6.0 \text{ Vdc}, V_{BE} = 0)$ $(V_{CE} = -6.0 \text{ Vdc}, V_{BE} = 0, T_{A} = 65^{\circ}\text{C})$ | ICES      |      | -0.01<br>-1.0 | μAdc |
| Base Current $(V_{CE} = -6.0 \text{ Vdc}, V_{EB} = 0)$   | lΒ        | _    | -10           | nAdc |

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.



#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (Continued)

| Characteristic   |  |                  | Min                | Max                   | Unit |
|--|--|------------------|--------------------|-----------------------|------|
| ON CHARACTERIS   | TICS(1)  | •                |                    | •                     |      |
| DC Current Gain ( $I_C = -10 \text{ mAdc}$ , $V_{CE} = -0.3 \text{ Vdc}$ ) ( $I_C = -50 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ )  |  | hFE              | 30<br>20           | 120<br>—              | _    |
| Collector – Emitter Saturation Voltage ( $I_C = -10 \text{ mAdc}$ , $I_B = -1.0 \text{ mAdc}$ ) ( $I_C = -50 \text{ mAdc}$ , $I_B = -5.0 \text{ mAdc}$ ) ( $I_C = -10 \text{ mAdc}$ , $I_B = -1.0 \text{ mAdc}$ , $I_A = 65^{\circ}\text{C}$ ) |  | VCE(sat)         | _<br>_<br>_<br>_   | -0.2<br>-0.6<br>-0.25 | Vdc  |
| Base-Emitter Saturat<br>(I <sub>C</sub> = -10 mAdc, I <sub>B</sub><br>(I <sub>C</sub> = -10 mAdc, I <sub>B</sub><br>(I <sub>C</sub> = -50 mAdc, I <sub>B</sub>   | = -0.5 mAdc)<br>= -1.0 mAdc)   | VBE(sat)         | -0.75<br>-0.75<br> | -0.95<br>-1.0<br>-1.5 | Vdc  |
| SMALL-SIGNAL C   | HARACTERISTICS   |                  |                    |                       |      |
| Current-Gain — Bandwidth Product<br>(I <sub>C</sub> = -10 mAdc, V <sub>CE</sub> = -5.0 Vdc, f = 100 MHz)   |  | fΤ               | 500                | _                     | MHz  |
| Output Capacitance<br>(V <sub>CB</sub> = -5.0 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)  |  | C <sub>obo</sub> | _                  | 3.5                   | pF   |
| Input Capacitance<br>(V <sub>EB</sub> = -0.5 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)   |  | C <sub>ibo</sub> | _                  | 3.5                   | pF   |
| SWITCHING CHAR   | ACTERISTICS  |                  |                    | •                     |      |
| Delay Time   | $(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -50 \text{ mAdc}, V_{BE(off)} = -1.9 \text{ Vdc},$      | t <sub>d</sub>   | _                  | 10                    | ns   |
| Rise Time  | $I_{B1} = -5.0 \text{ mAdc}$   | t <sub>r</sub>   |                    | 30                    | ns   |
| Storage Time   | $(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -50 \text{ mAdc}, I_{B1} = I_{B2} = -5.0 \text{ mAdc})$ | t <sub>S</sub>   |                    | 20                    | ns   |
| Fall Time  | 1  | t <sub>f</sub>   |                    | 12                    | ns   |
| Turn–On Time $(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -50 \text{ mAdc}, I_{B1} = -5.0 \text{ mAdc})$ $(V_{CC} = -1.5 \text{ Vdc}, I_{C} = -10 \text{ mAdc}, I_{B1} = -0.5 \text{ mAdc})$   |  | ton              | _<br>_             | 25<br>60              | ns   |
| Turn–Off Time $(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -50 \text{ mAdc}, I_{B1} = I_{B2} = -5.0 \text{ mAdc})$ $(V_{CC} = -1.5 \text{ Vdc}, I_{C} = -10 \text{ mAdc}, I_{B1} = I_{B2} = -0.5 \text{ mAdc})$  |  | <sup>t</sup> off | _<br>_             | 35<br>75              | ns   |

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu s,$  Duty Cycle  $\leq$  2.0%.

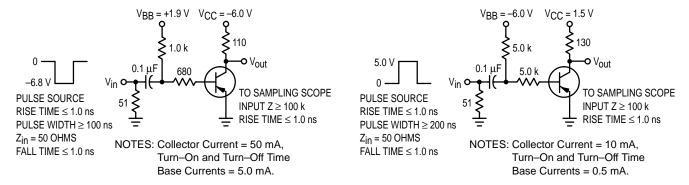


Figure 1. Figure 2.

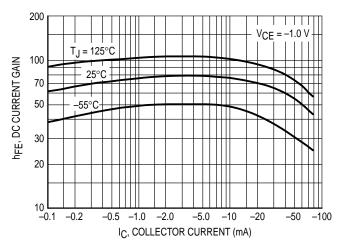


Figure 3. DC Current Gain

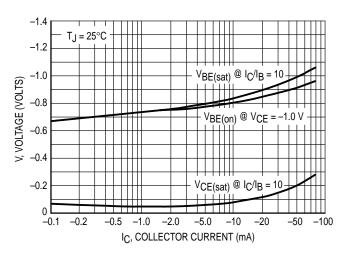


Figure 4. "On" Voltages

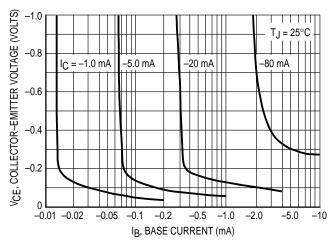
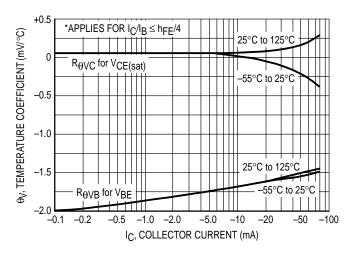


Figure 5. Collector Saturation Region



**Figure 6. Temperature Coefficients** 

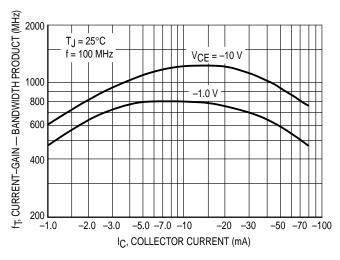


Figure 7. Current-Gain — Bandwidth Product

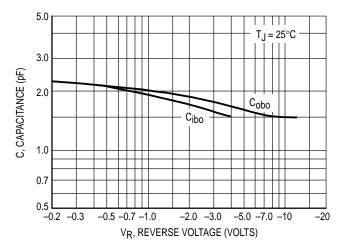
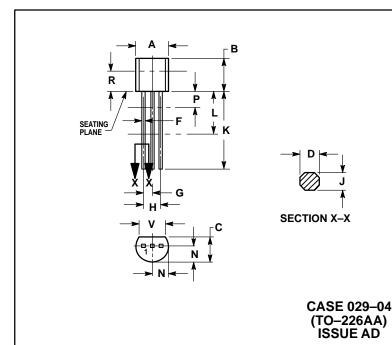


Figure 8. Capacitance

#### PACKAGE DIMENSIONS



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
  CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K
  MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|     | INCHES |       | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN    | MAX   | MIN    | MAX    |
| Α   | 0.175  | 0.205 | 4.45   | 5.20   |
| В   | 0.170  | 0.210 | 4.32   | 5.33   |
| C   | 0.125  | 0.165 | 3.18   | 4.19   |
| D   | 0.016  | 0.022 | 0.41   | 0.55   |
| F   | 0.016  | 0.019 | 0.41   | 0.48   |
| G   | 0.045  | 0.055 | 1.15   | 1.39   |
| Н   | 0.095  | 0.105 | 2.42   | 2.66   |
| 7   | 0.015  | 0.020 | 0.39   | 0.50   |
| K   | 0.500  |       | 12.70  |        |
| L   | 0.250  |       | 6.35   |        |
| N   | 0.080  | 0.105 | 2.04   | 2.66   |
| Р   |        | 0.100 |        | 2.54   |
| R   | 0.115  |       | 2.93   |        |
| ٧   | 0.135  |       | 3 43   |        |

STYLE 1: PIN 1. EMITTER BASE

3. COLLECTOR

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